TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

# 2 S C 2 8 8 4

### AUDIO FREQUENCY AMPLIFIER APPLICATIONS

- High DC Current Gain :  $h_{FE} = 100 \sim 320$
- Suitable for Output Stage of 1 Watts Amplifier
- PC=1~2W (Mounted on Ceramic Substrate)
- Small Flat Package
- Complementary to 2SA1204

#### MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$v_{CBO}$	35	V
Collector-Emitter Voltage	$v_{CEO}$	30	V
Emitter-Base Voltage	$v_{\mathrm{EBO}}$	5	V
Collector Current	$I_{\mathbf{C}}$	800	mA
Base Current	$I_{\mathrm{B}}$	160	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	500	mW
Collector Power Dissipation	P <sub>C</sub> (Note)	1000	mW
Junction Temperature	$T_{j}$	150	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C

Unit in mm

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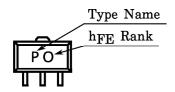
1.5±0.1

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Weight: 0.05g (Typ.)

(Note): Mounted on ceramic substrate (250mm<sup>2</sup>×0.8t)

#### **MARKING**



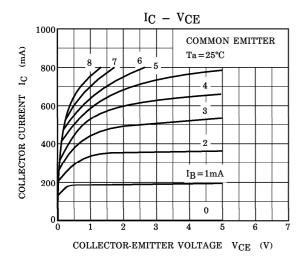
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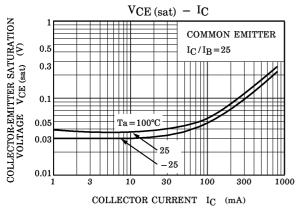
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

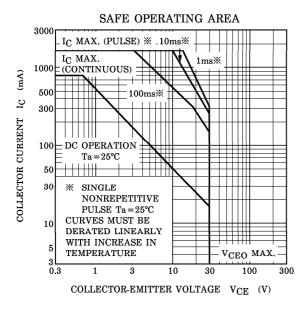
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 35V, I_{E} = 0$	_	_	0.1	$\mu$ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=5V, I_{C}=0$	_	_	0.1	$\mu$ A
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_{C}=10$ mA, $I_{B}=0$	30	_	_	V
DC Current Gain	hFE (1) (Note)	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	100	_	320	
	h <sub>FE (2)</sub>	$V_{\rm CE}$ =1V, I <sub>C</sub> =700mA	35	_	_	
Collector-Emitter Saturation Voltage	VCE (sat)	I <sub>C</sub> =500mA, I <sub>B</sub> =20mA	_	_	0.5	V
Base-Emitter Voltage	$ m V_{BE}$	$V_{\rm CE}=1V$ , $I_{\rm C}=10$ mA	0.5	_	0.8	V
Transition Frequency	$ m f_{T}$	$V_{\rm CE}$ =5V, $I_{\rm C}$ =10mA	_	120	_	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$	_	13	_	pF

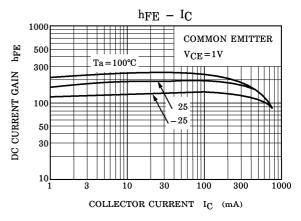
(Note) :  $h_{FE\,(1)}$  Classification O :  $100{\sim}200$ , Y :  $160{\sim}320$ 

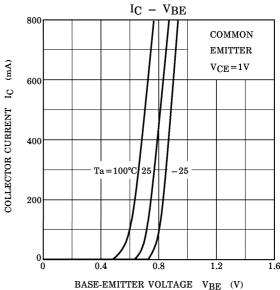
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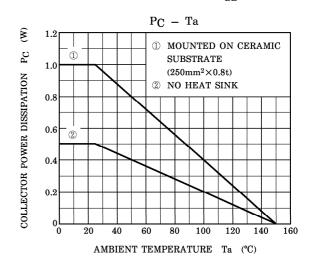












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